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# Magnetic properties and electron paramagnetic resonance spectra of CdGd<sub>2</sub>Se<sub>4</sub>

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Abstract. The magnetic susceptibility and the magnetization of polycrystalline  $CdGd_2Se_4$  were investigated. The data indicate that this compound exhibits an antiferromagnetic transition at 9.5 K. The effect of the dipolar interactions and the exchange coupling between the gadolinium ions in the crystal lattice were studied by analysis of the temperature dependence of the EPR linewidth.

#### 1. Introduction

 $CdGd_2Se_4$  is a magnetic semiconductor. It crystallizes in the cubic structure of the  $Th_3P_4$  type ( $I\bar{4}3d T_d^6$ ). The divalent cadmium atoms are randomly distributed among the metallic 12a positions. The unit cell contains four chemical molecules. More detailed data concerning the  $Th_3P_4$  structure may be found in the literature (Kripyakevich 1963, Methfessel 1964-5).

The magnetic properties of  $CdGd_2Se_4$  originate from the  ${}^8S_{7/2}$  ground multiplet of  $Gd^{3+}$ . We studied the magnetic susceptibility and magnetization of  $CdGd_2Se_4$ in order to determine the character of the magnetic ordering as well as to estimate the exchange coupling between the  $Gd^{3+}$  ions. These data were used further in the analysis of the EPR spectra. The discussion is referred to the earlier studies of  $Gd_2Se_3$  (Pokrzywnicki and Solik 1985) which has the same type but a cation-deficient structure.

#### 2. Experimental details

In the first step of the synthesis, binary CdSe and  $Gd_2Se_3$  were obtained. The reactions were performed in evacuated quartz ampoules at 700 °C and 900 °C, respectively. The stoichiometric mixture of these two materials was pressed into pellets in a dry box and heated to 760 °C. X-ray analysis showed the pure  $Th_3P_4$ -type structure with the lattice parameter a = 0.8860 nm. Because no additional lines were observed, we have excluded the occurrence of a superstructure. It means that the cadmium ions are distributed randomly among the 12a sites.

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The measurements of magnetization were performed in an extracting sample magnetometer in magnetic fields up to 14 T at different temperatures. These measurements were made at the Institute for Low Temperatures and Structure Research, Polish Academy of Science in Wrocław. Magnetic susceptibility measurements were carried out over the temperature range 4.2–300 K by a Faraday method using a Cahn RH electrobalance.

The EPR spectra have been measured using an X-band spectrometer (9.26 GHz) in the temperature range 4.2-300 K.

### 3. Results and discussion

The plot of the inverse magnetic susceptibility of  $CdGd_2Se_4$  is presented in figure 1. In the paramagnetic region it obeys the Curie-Weiss law. The values of the paramagnetic Curie temperature  $\Theta_p$  and the effective magnetic moment are 11.5 K and  $8.03 \ \mu_B$ , respectively (the thoretical value of the Gd<sup>3+</sup> moment is 7.94  $\mu_B$ ). At the temperature  $T_N = 9.5 \pm 0.5$  K the compound shows an antiferromagnetic transition. The close values of  $\Theta_p$  and  $T_N$  indicate that the material is a Néel-type antiferromagnet.



Figure 1. Magnetic susceptibility of CdGd<sub>2</sub>Se<sub>4</sub>: O, experimental points.

The magnetizations at 4.21, 20 and 40 K are presented in figure 2. The magnetization at 4.2 K in the srongest magnetic field (14 T) is equal to 6.23  $\mu_{\rm B}$  per Gd atom; it is somewhat lower than the value in the completely saturated state (7  $\mu_{\rm B}$ ).

Asymmetric EPR lines arising from the  ${}^{8}S_{7/2}$  manifold of the Gd<sup>3+</sup> ions were obtained. The value of the *g*-factor, the EPR lineshape and linewidth were examined as functions of temperature which gave information on the spin interaction mechanisms in the system. Two EPR spectra taken at room temperature and 30 K are presented in figure 3 as first derivatives of the absorbed power versus magnetic field. Both positive and negative frequency components of the dynamic susceptibility should be taken into account in the analysis of the lineshape since linewidths comparable with



Figure 2. Magnetization of CdGd<sub>2</sub>Se<sub>4</sub> at different temperatures: O, experimental points.

the resonant field were observed. Thus the average power absorbed in a sample is  

$$P(H) \sim [[(H/\Delta H)/\{1 + [(H - H_r)/\Delta H]^2\}] + (H/\Delta H)/\{1 + [(H + H_r)/\Delta H]^2\}] + b_0([(H - H_r)/\Delta H][[(H/\Delta H)/\{1 + [(H - H_r)/\Delta H]^2\}]] + [(H + H_r)/\Delta H][[(H/\Delta H)/\{1 + [(H + H_r)/\Delta H]^2\}]]$$
(1)

where  $H_r$  is the resonant field,  $\Delta H$  the half-width and  $b_0$  a factor determining the admixture of the absorptive and dispersive parts of the dynamic susceptibility.

The evaluations of  $\Delta H$ ,  $H_r$  and g at different temperatures were made following the method described by Sugawara *et al* (1983).

Figure 4 shows the EPR linewidth versus temperature. It is seen that the linewidth increases rapidly when the temperature approaches  $T_N$  while at higher temperatures the dependence becomes less significant. The g-factor is equal to  $2.02 \pm 0.01$  in the temperature range studied.

The EPR linewidth above the ordering temperature depends on the relaxation rate of the system of interacting magnetic ions (Kawasaki 1968, Huber 1972). In ferromagnets the main contributions to the relaxation function come from wavevectors near the centre of the Brillouin zone. In antiferromagnets an important role is played by wavevectors near the superlattice vector for the ordered state. This contribution is usually strongly temperature dependent and is responsible for the line broadening near  $T_N$ . It is useful (Huber 1972) to separate the critical and non-critical parts of the relaxation rate:

$$1/T_2(T) \simeq \Delta(1/T_2) + 1/T_2(\infty)$$
 (2)

where  $T_2(\infty)$  is the high-temperature limit of the relaxation time. A similar equation may be written for EPR linewidth:

$$\Delta H(T) \simeq \Delta H_{\rm c}(T) + \Delta H_{\infty} \tag{3}$$



Figure 3. First derivatives of EPR spectra: curve 1, room temperature; curve 2, 30 K.



Figure 4. The EPR linewidth versus temperature for  $CdGd_2Se_4$ : O, experimental results; -----, result of the fitting.

where  $\Delta H_{\infty}$  is the high-temperature limit of the linewidth.  $\Delta_{\rm c}(H)$  arises from the critical part of the relaxation rate  $\Delta(1/T_2)$  and reflects a line broadening near the ordering temperature.

For a system with Néel temperature  $T_N$  the linewidth versus temperature is ex-

pressed as

$$\Delta H(T) \simeq \Delta H_{\infty} + A \left( T/T_{\rm N} - 1 \right)^{-p} \tag{4}$$

where  $\Delta H_{\infty}$  is the high-temperature limit of  $\Delta H$ .  $\Delta H_{\infty}$ , A and p were fitted to the experimental  $\Delta H(T)$  plot and the result is presented in figure 4 as the full curve. The parameters calculated for CdGd<sub>2</sub>Se<sub>4</sub> are given in table 1 and compared with parameters for Gd<sub>2</sub>Se<sub>3</sub> (Pokrzywnicki and Solik 1985).

Compound	$\Delta H_{\infty}$ (mT)	A (mT)	р	
CdGd <sub>2</sub> Se <sub>4</sub>	83.6	151.6	0.517	
$Gd_2Se_3$	92.1	127.3	0.480	

Table 1. Best-fit parameters of equation (4).

No significant differences have been found between the parameters obtained for the two selenides. This indicates a similarity of the gadolinium-selenium chemical bond.  $Gd_2Se_3$  crystallizes in the metal-deficient  $Th_3P_4$  structure. The molecule may be described as  $Gd_{8/3}\Box_{1/3}Se_4$ , where  $\Box$  stands for a void. The unit cell contains 10.67 cations randomly distributed between 12 possible metal positions. The absolute values of the Néel temperature and the Curie temperature for  $Gd_2Se_3$  (6 K and -10 K, respectively) are lower than the corresponding quantities for  $CdGd_2Se_4$  (9.5 K and -11.5 K).

The main factors influencing the behaviour of the observed EPR linewidth are dipolar interactions and the exchange coupling between the gadolinium ions. A rough estimate of  $\Delta H(\infty)$  may be achieved using the moment method (Abragam 1961):

$$\Delta H_{\infty} = \sqrt{\pi/2} \, M_2^{3/2} / M_4^{1/2} \tag{5}$$

where  $M_2$  denotes the second moment of the dipolar interaction and  $M_4$  is the fourth moment which contains both dipolar and exchange interactions.

We have estimated  $\Delta H_{\infty}$  taking into account the interactions with ions from the first and second coordination spheres only. The corresponding exchange integrals  $J_1 = -0.03$  K and  $J_2 = -0.34$  K were calculated in the molecular-field approximation (Smart 1966). The estimated value of  $\Delta H_{\infty} = 86$  mT is close to the value obtained by the fitting of equation (2) to the experimental  $\Delta H(T)$  plot. The values of two remaining parameters of that equation, namely A and p, do not differ significantly for either CdGd<sub>2</sub>Se<sub>4</sub> or Gd<sub>2</sub>Se<sub>3</sub>. The absolute value of the p exponent is lower than that predicted by the RPA calculation  $(\frac{3}{2})$ . Similar deviations were reported in other work (Baran *et al* 1980, Kuriata *et al* 1988).

The magnetic dipolar interaction in  $CdGd_2Se_4$  is weaker than that in  $Gd_2Se_3$  because of the lower concentration of the gadolinium ions. The broadening of the linewidth for  $CdGd_2Se_4$  may come from weaker exchange interactions with the nearest neighbours of a magnetic atom and stronger antiferromagnetic interactions with the next neighbours, in comparison with  $Gd_2Se_3$ .

A more distinct change in the exchange mechanism is expected when a magnetic metal (e.g. manganese and iron) replaces the cadmium.

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